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PATENT NUMBER and **ISSUE DATE**

APPL NUM FILING DATE CLASS SUBCLASS GAIJ **EXAMINER** 10052347 01/23/2002 438 2812 *APPLICANTS: Manabe Katsuhide; Mabuchi Akira; Kato Hisaki; Sassa Michinari; Koide Norikatsu; Yamazaki Shiro; Hashimoto Masafumi; Akasaki Isamu; **CONTINUING DATA VERIFIED: THIS APPLICATION IS A CON OF 09/677,781 10/02/2000 WHICH IS A DIV OF 09/417,778 10/14/1999 WHICH IS A DIV OF 08/956,950 10/23/1997 PAT 6,249,012 |WHICH IS A DIV OF 08/556,232 11/09/1995 PAT 5,733,796 WHICH IS A CON OF 08/179,242 01/10/1994 ABN WHICH IS A DIV OF 07/926,022 08/07/1992 PAT 5,278,433 WHICH IS A CON OF 07/661,30∜ 02/27/1991 ABN * FOREIGN APPLICATIONS VERIFIED: JAPAN P050209/1990 02/28/1990 JAPAN P050210/1990 02/28/1990 JAPAN P050211/1990 02/28/1990 PG-PUB DO NOT PUBLISH 🗖 RESCIND -Foreign priority claimed 🗆 yes 🗆 no ATTORNEY DOCKET NO 35 USC 119 conditions met 🗆 yes 🕽 no Verified and Acknowledged Examiners's intials P 282475 F00-219-USdiv3-c TITLE: Method for manufacturing a gallium nitride group compound semiconductor

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED			
	Assistant Examiner	Total Claims		Print Claim for O.G	
ISSUE FEE		DRAWING			
Amount Due Date Paid		Sheets Drwg.	Figs.Drwg	Print Fig.	
	Primary Examiner	7			
TERMINAL	PREPARED FOR ISSUE	Application Examiner			
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